NSN 5961-01-309-1370

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-309-1370 **Inclosure Material:** Glass **Overall Length:** 0.357 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.235 inches **Mounting Method: Terminal** Features Provided: Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 23.1 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 1.5 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli

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